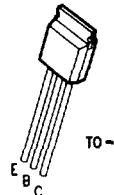




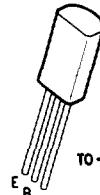
2N6729

MPS6729



TO - 237

TL/G/10100-8



TO - 228AE

TL/G/10100-4

PNP General Purpose Amplifier

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(\text{BR})\text{CEO}}$	Collector-Emitter Breakdown Voltage, (Note 1) ($I_C = 1.0 \text{ mA}_\text{dc}, I_B = 0$)	80		Vdc
$V_{(\text{BR})\text{CBO}}$	Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{A}_\text{dc}, I_E = 0$)	80		Vdc
$V_{(\text{BR})\text{EBO}}$	Emitter-Base Breakdown Voltage ($I_E = 10 \mu\text{A}_\text{dc}, I_C = 0$)	5.0		Vdc
I_{EBO}	Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_E = 0$)		10	μA_dc
I_{CBO}	Collector Cutoff Current ($V_{CB} = 60 \text{ Vdc}, I_C = 0$)		0.1	μA_dc
ON CHARACTERISTICS (Note 1)				
h_{FE}	DC Current Gain ($I_C = 50 \text{ mA}_\text{dc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 250 \text{ mA}_\text{dc}, V_{CE} = 1.0 \text{ Vdc}$)	80 50	250	
$V_{\text{CE}(\text{sat})}$	Collector-Emitter Saturation Voltage ($I_C = 250 \text{ mA}_\text{dc}, I_B = 10 \text{ mA}_\text{dc}$)		0.5	Vdc
$V_{\text{BE}(\text{on})}$	Base-Emitter On Voltage ($I_C = 250 \text{ mA}_\text{dc}, V_{CE} = 1.0 \text{ Vdc}$)		1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS				
C_{cb}	Collector-Base Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$)		30	pF
h_{fe}	Small-Signal Current Gain ($I_C = 200 \text{ mA}_\text{dc}, V_{CE} = 5.0 \text{ Vdc}, f = 20 \text{ MHz}$)	2.5	25	

Note 1: Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

Note 2: For characteristics curves, see Process 79.